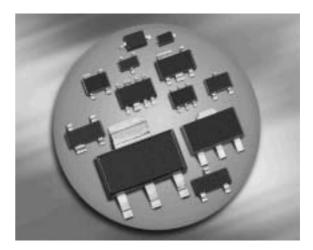


Silicon Variable Capacitance Diode

- For UHF-TV tuners
- Large capacitance ratio, low series resistance
- Pb-free (RoHS compliant) package¹⁾
- Qualified according AEC Q101





SD197



Туре	Package	Configuration	L _S (nH)	Marking
SD197E6552	SOD323	single	1.8	white S

Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit				
Diode reverse voltage	V _R	30					
Peak reverse voltage-	V _{RM}	35					
Forward current	I _F	20	mA				
Operating temperature range		-55 125	°C				
Storage temperature	T _{stg}	-55 150					

¹Pb-containing package may be available upon special request



Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					-
Reverse current	I _R				nA
$V_{\rm R} = 30 {\rm V}$		-	-	10	
$V_{\rm R} = 30 \text{ V}, \ T_{\rm A} = 85 \text{ °C}$		-	-	200	
AC Characteristics					
Diode capacitance	CT				pF
$V_{R} = 2 V, f = 1 MHz$		14.16	15	16.25	
$V_{\rm R} = 25 \text{ V}, f = 1 \text{ MHz}$		2.11	2.24	2.43	
Capacitance ratio	C _{T2} /C _{T25}	6.3	6.7	7	-
$V_{\rm R} = 2$ V, $V_{\rm R} = 25$ V, $f = 1$ MHz					
Capacitance matching ¹⁾	$\Delta C_{\rm T}/C_{\rm T}$	-	-	1.2	%
$V_{\rm R}$ = 2 25 V, f = 1 MHz, 8 diodes sequence					
Series resistance	r _S	-	0.55	0.65	Ω
V _R = 3 V, <i>f</i> = 470 MHz					

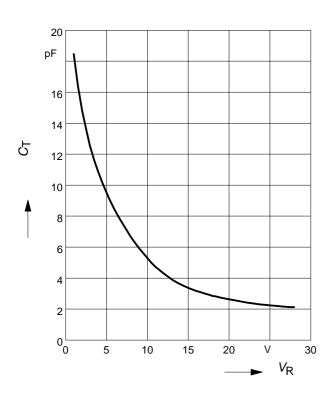
Electrical Characteristics at $T_A = 25^{\circ}$ C, unless otherwise specified

¹For details please refer to Application Note 047.



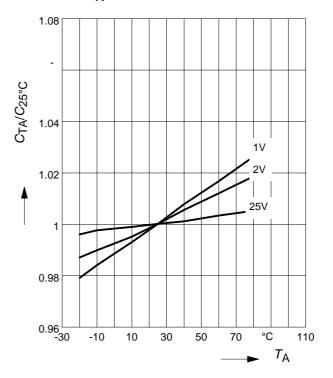
Diode capacitance $C_{T} = f(V_{R})$

f = 1 MHz

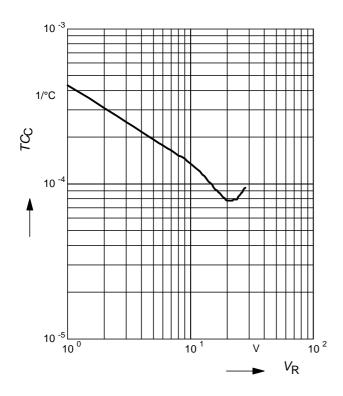


Normalized diode capacitance

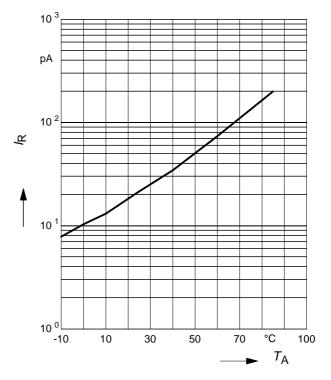
 $C_{(TA)}/C_{(25^{\circ}C)} = f(T_A);$ f = 1MHz, V_R = Parameter



Temperature coefficient of the diode capacitance $T_{Cc} = f(V_R)$



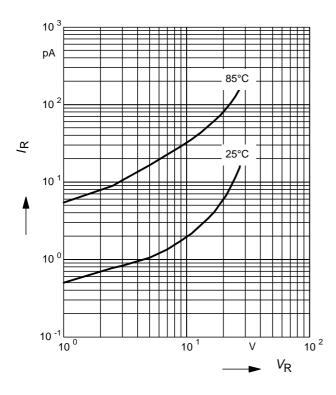
Reverse current $I_{R} = f(T_{A})$ $V_{R} = 28 \text{ V}$



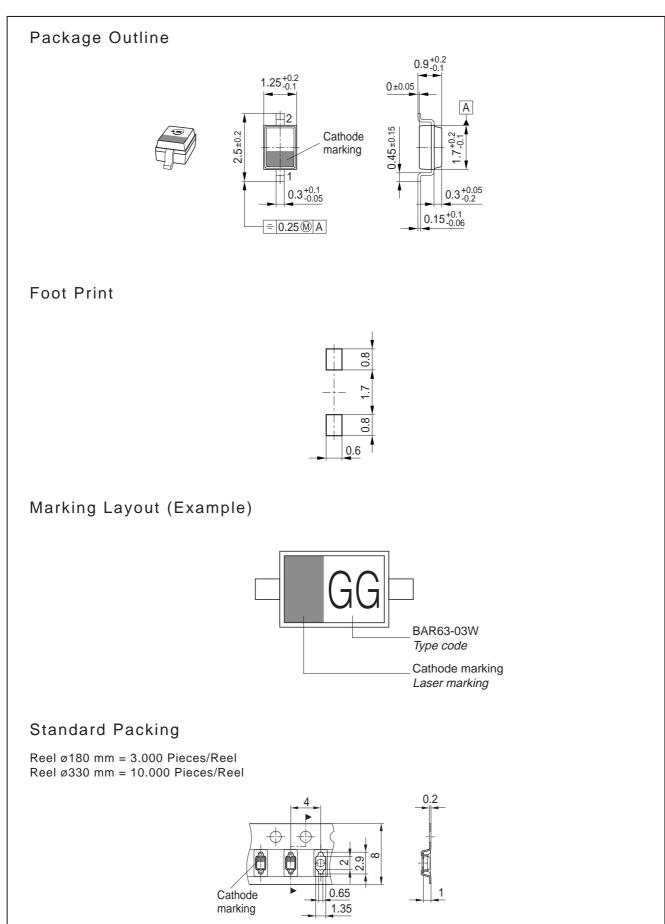


Reverse current $I_{\rm R} = f(V_{\rm R})$

 T_A = Parameter









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